SLLS116A - D2298, JANUARY 1977 - REVISED JANUARY 1993

- Schottky Circuitry for High Speed, Typical Propagation Delay Time . . . 12 ns
- Drivers Feature Open-Collector Outputs for Party-Line (Data Bus) Operation
- Driver Outputs Can Sink 100 mA at 0.8 V Maximum
- PNP Inputs for Minimal Input Loading
- Designed to Be Interchangeable With Advanced Micro Devices AM26S10 and AM26S11

D OR N PACKAGE (TOP VIEW)								
evio q	· Γ.	U	, L.,					
GND [1B [2	15] ∨ _{CC}] 4B					
1R [3	14	4R					
1D [4	13	4D					
2D [2R [5	12 11]s]3D					
2B [7	10] 3R					
GND [8	9] 3B					

description

The AM26S10C and AM26S11C are quadruple bus transceivers utilizing Schottky-diode-clamped transistors for high speed. The drivers feature open-collector outputs capable of sinking 100 mA at 0.8 V maximum. The driver and strobe inputs use pnp transistors to reduce the input loading.

The driver of the AM26S10C is inverting; the driver of the AM26S11C is noninverting. Each device has two ground connections for improved ground current-handling capability. For proper operation, the ground pins should be tied together.

The AM26S10C and AM26S11C are characterized for operation over the temperature range of 0°C to 70°C.

Function Tables

AM26S10C (transmitting)

INP	UTS	OUTPUTS			
s	D	В	R		
L	Н	L	Н		
L	L	Ιн	L		

AM26S11C (transmitting)

(.,, _,,								
INP	UTS	ουτι	PUTS					
S	D	В	R					
L	Н	Н	L					
L	L	L	н					

AM26S10C AND AM26S11C (receiving)

	INPUTS	OUTPUT	
S	8	D	R
Н	Н	×	L
н	L	X	Н

H = high level, L = low level, X = irrelevant

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas instruments standard warranty. Production processing does not necessarily include testing of all parameters.



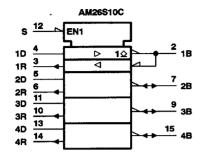
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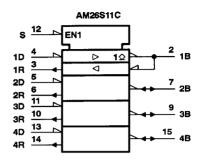
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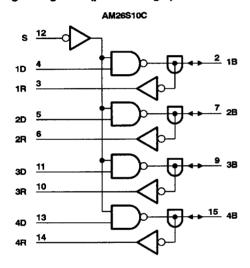
logic symbols†

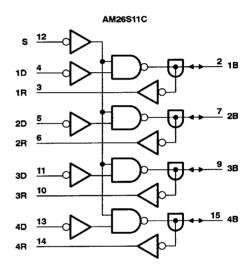




[†] These symbols are in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

logic diagrams (positive logic)





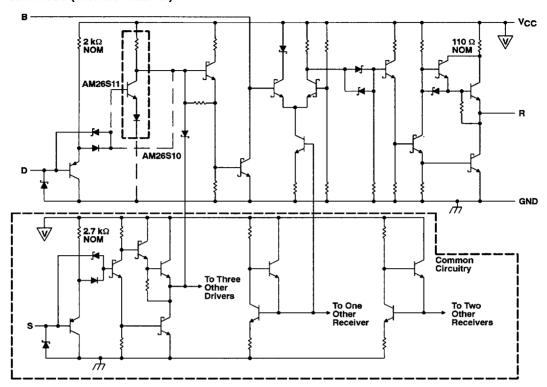


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schematic (each transceiver)





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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

Supply voltage, V _{CC} (see Note 1)	0.5 V to 7 V
Driver or strobe input voltage range, V ₁	0.5 V to 5.5 V
Bus voltage range, driver output off, VO	0.5 V to 5.25 V
Driver or strobe input current range, I ₁	30 mA to 5 mA
Driver output current, IO	200 mA
Receiver output current, IO	30 mA
Continuous total power dissipation	See Dissipation Rating Table
Operating free-air temperature range	0°C to 70°C
Storage temperature range	65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	260°C

NOTE 1: All voltage values are with respect to network ground terminals connected together.

DISSIPATION RATING TABLE

PACKAGE	T _A ≤ 25°C POWER RATING	DERATING FACTOR ABOVE T _A = 25°C	T _A = 70°C POWER RATING		
D	950 mW	7.6 mW/°C	608 mW		
N	1150 mW	9.2 mW/°C	736 mW		

recommended operating conditions

		MIN	NOM	MAX	UNIT	
Supply voltage, V _{CC}		4.75	5	5.25	V	
High lavael income values No.	D or S	2			>	
ligh-levael input voltage, V _{IH}	В	2.25				
Law level input veltage Vi-	D or S			0.8	v	
Low-level input voltage, V _{IL}	В			1.75	V	
Receiver high-level output current, le	ЭН			-1	mA	
1 and level and and arrest to 1	Driver			100	mA	
Low-level output current, IOL	Receiver			20		
Operating free-air temperature, TA		0		70	°C	



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electrical characteristics over recommended operating free-air temperature range

PARAMETER			TEST CONDITIONS				TYP	MAX	UNIT
Vik	Input clamp voltage	D or S	V _{CC} = 4.75 V _i	I _I = -18 mA				-1.2	>
Voн	High-level output voltage	R	V _{CC} = 4.75 V, I _{OH} = -1 mA	V _{IH} = 2 V,	VIL = 0.8 V,	2.7	3.4		>
		R			I _{OL} = 20 mA			0.5	
	1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1		V _{CC} = 4.75 V,	V _{IH} = 2 V,	I _{OL} = 40 mA		0.33	0.5	٧
VOH	Low-level output voltage	В	V _{IL} = 0.8 V	•••	I _{OL} = 70 mA		0.42	0.7	
1		1			I _{OL} = 100 mA		0.51	0.8	
				V _{CC} = 5.25 V,	V _O = 0.8 V			-50	ا 🗚 🔁
lO(off)	Off-stage output current	В	V _{IH} = 2 V, V _{IL} = 0.8 V	V _{CC} = 5.25 V,	V _O = 4.5 V			100	
- (,				V _{CC} = 0,	V _O = 4.5 V			100	
		D	V F05V	V _I = 2.7 V				30	μА
lН	High-level input current	s	V _{CC} = 5.25 V _i					20	μ
1 ₄	Input current at maximum input voltage	D or S	V _{CC} = 5.25 V,	V _I = 5.5 V				100	μА
_		D						-0.54	mA
ΙL	Low-level input current	s	V _{CC} = 5.25 V,	$V_i = 0.4 \text{ V}$				-0.36	ША
los	Short-circuit output current‡	R	V _{CC} = 5.25 V			-18		-60	mA
			V _{CC} = 5.25 V,	Strobe at 0 V,	No load,		45	70	mA
ICC	Supply current		All driver outputs low				80	IIIA	

switching characteristics, $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$

		FROM	TO	TEST	Al	/126S10	C	Al	M26S110	,	UNIT					
	PARAMETER	(INPUT)	(OUTPUT)	CONDITIONS	MIN	TYP	MAX	MIN	TYP	MAX	ONII					
tPLH	Propagation delay time, low-to-high-level output	D	В			10	15		12	19	ns					
tPHL	Propagation delay time, high-to-low-level output	В	В	1		10	15		12	19	,,,,					
tPLH	Propagation delay time, low-to-high-level output	\$					•	В			14	18		15	20	ns
tPHL	Propagation delay time, high-to-low-level output			See Figure 1		13	18		14	20	115					
tPLH	Propagation delay time, low-to-high-level output	В				10	15	*	10	15	ns					
tPHL	Propagation delay time, high-to-low-level output						10	15		10	15	,,,,				
tтLН	Transition time, low-to-high-level output		В	В		4	10		4	10		ns				
tTHL	Transition time, high-to-low-level output					2	4		2	4						

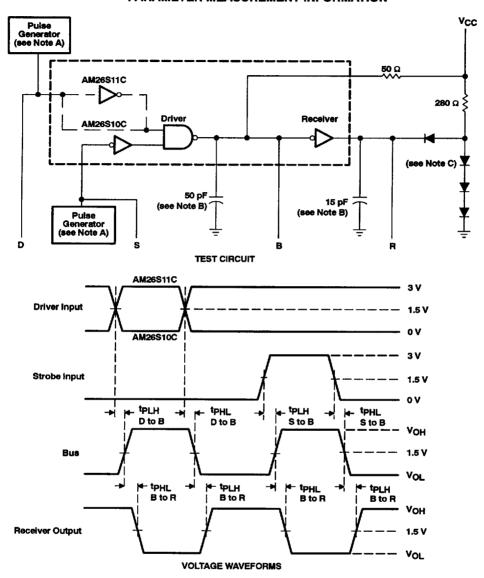


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[†] All typical values are at T_A = 25°C and V_{CC} = 5 V.
‡ Not more than one output should be shorted to ground at a time, and duration of the short circuit should not exceed one second.

PARAMETER MEASUREMENT INFORMATION



- NOTES: A. The pulse generators have the following characteristics: Z_0 = 50 Ω , $t_{\rm f}$ = 10 ± 5 ns.
 - B. Includes probe and jig capacitance.
 - C. All diodes are 1N916 or equivalent.

Figure 1. Test Circuit and Voltage Waveforms



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APPLICATION INFORMATION

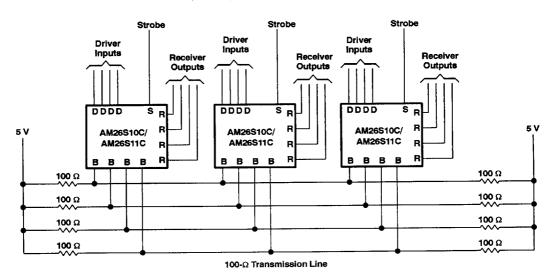


Figure 2. Party-Line System



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